

Appl. No. 09/545,785
Amendment and/or Responses
Reply to Office action of 20 May 2003

24 / E
Page 1 of 13
w/ Drawing 3
Attach.

9/3/03
Mollisi

IN THE UNITED STATES
PATENT AND TRADEMARK OFFICE

Appl. No. : 09/545,785 ✓
Applicants : Tirdad SOWLATI et al.
Filed : 7 April 2000 ✓
TC/A.U. : 2811
Examiner : Ori NADAV
Atty. Docket : US000099A

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Title: INTERDIGITATED MULTILAYER CAPACITOR
STRUCTURE FOR DEEP SUB-MICRON CMOS

AMENDMENT and/or RESPONSE under 37 C.F.R. § 1.112

Mail Stop **Non-Fee Amendment**
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the non-final Office action of 20 May 2003, please amend the
above referenced application as follows and reconsider the application in light of the
following remarks.

This paper includes (each beginning on a separate sheet):

1. Listing of the claims;
2. Amendments to the drawing figures;
3. Remarks/Discussion of issues;
4. Attached replacement drawing sheet;
5. Annotated drawing sheet showing changes.

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